

# APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

High Q / Low ESR Series (HH)

0402, 0603 & 0805 Sizes

**NP0** Dielectric

**RoHS Compliance** 

\*Contents in this sheet are subject to change without prior notice.



#### 1. INTRODUCTION

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used.

WTC HH series MLCC is used at high frequencies generally have a small temperature coefficient of capacitance, typical within the ±30ppm/°C required for NP0 (C0G) classification and have excellent conductivity internal electrode. Thus, WTC HH series MLCC will be with the feature of low ESR and high Q characteristics.

#### 2. FEATURES

- a. High Q and low ESR performance at high frequency.
- b. Quality improvement of telephone calls for low power loss and better performance.

#### 3. APPLICATIONS

- a. Mobile telecommunication: Mobile phone, WLAN.
- b. RF module: Power amplifier, VCO.
- c. Tuners.

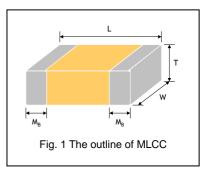
#### 4. HOW TO ORDER

<u>HH</u>	<u>15</u>	<u>N</u>	<u>100</u>	<u>G</u>	<u>500</u>	<u>C</u>	I
<u>Series</u>	<u>Size</u>	Dielectric	<u>Capacitance</u>	<u>Tolerance</u>	Rated voltage	<u>Termination</u>	<u>Packaging</u>
<b>HH</b> =High Q/ Low ESR	<b>15</b> =0402 (1005) <b>18</b> =0603 (1608) <b>21</b> =0805 (2012)	<b>N</b> =NP0 (C0G)	Two significant digits followed by no. of zeros. And R is in place of decimal point.	B=±0.1pF C=±0.25pF D=±0.5pF F=±1% G=±2%	Two significant digits followed by no. of zeros. And R is in place of decimal point.	L=Ag/Ni/Sn C=Cu/Ni/Sn	T=7" reeled G=13" reeled
			eg.: R47=0.47pF 0R5=0.5pF 1R0=1.0pF 100=10x10 <sup>0</sup> =10pF	<b>J</b> =±5%	160=16 VDC 250=25 VDC 500=50 VDC 101=100 VDC 201=200 VDC 251=250 VDC 501=500 VDC 631=630 VDC		



## **5. EXTERNAL DIMENSIONS**

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbol		Remark	M <sub>B</sub> (mm)	
0402 (1005)	1.00±0.05	0.50±0.05	0.50±0.05	N	#	0.25 +0.05/-0.10	
0000 (4000)	1.60±0.10	0.80±0.10	0.80±0.07	s		0.40.045	
0603 (1608)	1.60 +0.15/-0.10	0.80 +0.15/-0.10	0.80 +0.15/-0.10	х		0.40±0.15	
			0.60±0.10	Α			
0805 (2012)	2.00±0.15	1.25±0.10	0.80±0.10	В		0.50±0.20	
			1.25±0.10	D	#		



# **6. GENERAL ELECTRICAL DATA**

Dielectric	NP0			
Size	0402, 0603, 0805			
	0402: 0.5pF to 470pF**			
Capacitance*	0603: 0.5pF to 3300pF			
	0805: 0.5pF to 390pF			
	Cap≤5pF: B (±0.1pF), C (±0.25pF)			
Capacitance tolerance	5pF <cap<10pf: (±0.25pf),="" (±0.5pf)<="" c="" d="" td=""></cap<10pf:>			
	Cap≥10pF: F (±1%), G (±2%), J (±5%)			
Rated voltage (WVDC)	16V, 25V, 50V, 100V, 200V, 250V, 500V, 630V			
Q*	Cap<30pF: Q≥400+20C			
<b>u</b> *	Cap≥30pF: Q≥1000			
Insulation resistance at Ur	≥10GΩ or RxC≥100Ω-F whichever is smaller.			
Operating temperature	-55 to +125℃			
Capacitance change ±30ppm				
Termination	Ni/Sn (lead-free termination)			

 $<sup>^{\</sup>star}$  Measured at the conditions of 25°C ambient temper ature and 30~70% related humidity.

Apply 1.0±0.2Vrms, 1.0MHz±10% for Cap≤1000pF and 1.0±0.2Vrms, 1.0kHz±10% for Cap>1000pF.

<sup>#</sup> Reflow soldering only is recommended.

<sup>\*\* 0402,</sup> Capacitance <0.5pF: On request.



# 7. CAPACITANCE RANGE

	DIELECTRIC							NP0						
	SIZE		0402			06		-			08	05		
	Rated Voltage	16	25	50	16	25	50	100	50	100	200	250	500	630
	0.5pF (0R5)	N^	N^	N^	S^	S^	S^	S^	В	В				
	0.6pF (0R6)	N^	N^	N^	S^	S^	S^	S^	В	В				
	0.7pF (0R7)	N^	N^	N^	S^	S^	S^	S^	В	В				
	0.8pF (0R8)	N^	N^	N^	S^	S^	S^	S^	В	В				
	0.9pF (0R9)	N^	N^	N^	S^	S^	S^	S^	В	В				
	1.0pF (1R0)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	1.2pF (1R2)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	1.5pF (1R5)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	1.8pF (1R8)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	2.2pF (2R2)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	2.7pF (2R7)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	3.3pF (3R3)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	3.9pF (3R9)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	4.7pF (4R7)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	5.6pF (5R6)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	6.8pF (6R8)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	8.2pF (8R2)	N^	N^	N^	S^	S^	S^	S^	В	В	В	В	В	В
	10pF (100)	N	N	N	S	S	S	S	В	В	В	В	В	В
	12pF (120)	N	N	N	S	S	S	S	В	В	В	В	В	В
	15pF (150)	N	N	N	S	S	S	S	В	В	В	В	В	В
	18pF (180)	N	N	N	S	S	S	S	В	В	В	В	В	В
	22pF (220)	N	N	N	S	S	S	S	В	В	В	В	В	В
ü	27pF (270)	N	N	N	S	S	S	S	В	В	В	В	В	В
Capacitance	33pF (330)	N	N	N	S	S	S	S	В	В	В	В	В	В
bac	39pF (390)	N	N	N	S	S	S	S	В	В	В	В	В	В
င်ဒ	47pF (470)	N	N	N	S	S	S	S	В	В	В	В	В	В
	56pF (560)	N	N	N	S	S	S	S	В	В	В	В	В	В
	68pF (680)	N	N	N	S	S	S	S	В	В	В	В	В	В
	82pF (820)	N	N	N	S	S	S	S	В	В	В	В	В	В
	100pF (101)	N	N	N	S	S	S	S	В	В	В	В	В	В
	120pF (121)	N	N	N	S	S	S	S	D	D	D	D	D	D
	150pF (151)	N	N	N	S	S	S	S	D	D	D	D	D	D
	180pF (181)	N	N	N	S	S	S	S			D	D	D	D
	220pF (221)	N N	N	N N	S S	S	S	S			D	D D	D D	D
	270pF (271)	N N	N N	N N	S	S	S S	S			D D	D	D	D D
	330pF (331) 390pF (391)	N N	N	N N				S				D	D	
	470pF (471)	N N	N	N N	S S	S	S S	S			D	ט	ט	D
	560pF (561)	IN	IN	IN	S	S	S	S						
	680pF (681)				S	S	S	S						
	820pF (821)				S	S	S	S						
	1,000pF (102)				S	S	S	S						
	1,200pF (102)				X	X	X	3						
	1,500pF (152)				X	X	X							
	1,800pF (182)				X	X	X							
	2,200pF (222)				X	X	X							
	2,700pF (272)				X	X	X							
	3,300pF (332)				X	X	X							
	3,300pr (332)				^	_ ^	^							

<sup>1.</sup> The letter in cell is expressed the symbol of product thickness.

<sup>2.</sup> The letter in cell with "A" mark is expressed product with Ag/Ni/Sn terminations.

<sup>3. 0402,</sup> Capacitance <0.5pF: On request.

<sup>4.</sup> For more information about products with special capacitance or other data, please contact WTC local representative.



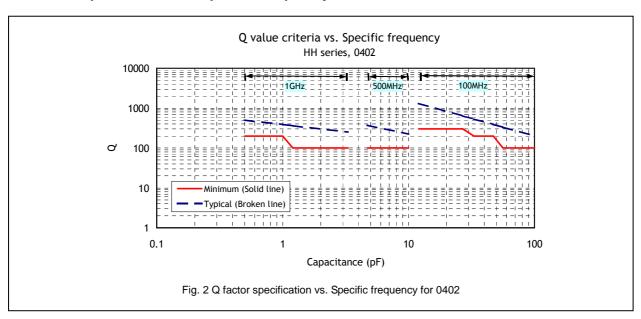
#### **8. PACKAGING DIMENSION AND QUANTITY**

Size	Thickness (mm)/Symbol		Pape	r tape	Plastic tape	
Size	THICKNESS (IIIII)/Sylli	JUI	7" reel	13" reel	7" reel	13" reel
0402	0.50±0.05	N	10K	20K		
0603	0.80±0.07	S	4K	15K		
0003	0.80 +0.15/-0.10	Х	41			
	0.60±0.10	Α	4k	15k		
0805	0.80±0.10	В	4K			
	1.25±0.10	D			3k	10k

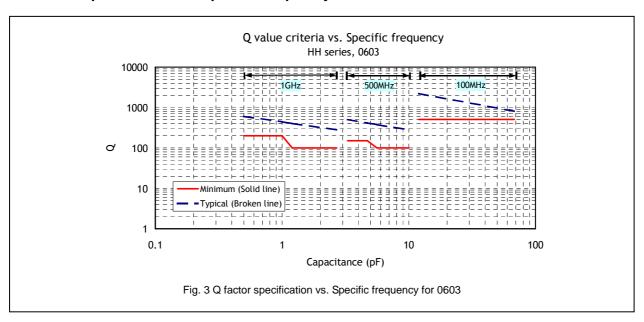
Unit: pieces

# 9. ELECTRICAL CHARACTERISTICS

#### **Q** factor specification vs. Specific frequency

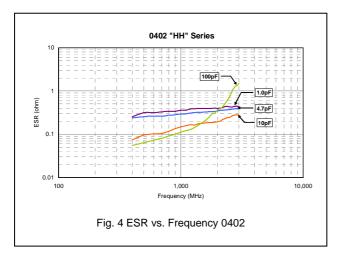


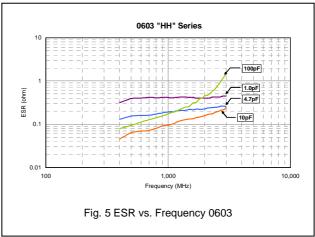
#### Q factor specification vs. Specific frequency



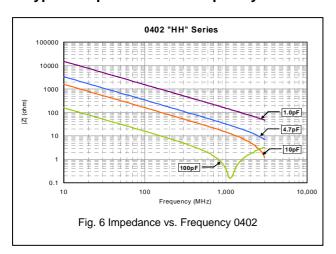


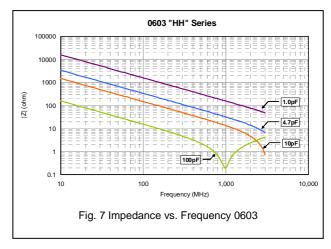
## **■** Typical ESR vs. Frequency



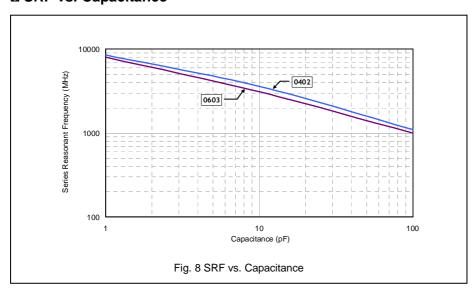


# **■** Typical Impedance vs. Frequency





## **■** SRF vs. Capacitance



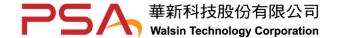


# 10. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Conditions		Requirements
1.	Visual and			* No remarkable defect.
	Mechanical			* Dimensions to conform to individual specification sheet.
2.	Capacitance	Cap≤1000pF, 1.0±0.2Vrms, 1MHz±10%		* Shall not exceed the limits given in the detailed spec.
3.	Q/ D.F.	Cap>1000pF, 1.0±0.2Vrms, 1KHz±10%		* NP0: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C
	(Dissipation	At 25℃ ambient temperature.		
	Factor)			
4.	Dielectric	* To apply voltage: ( ≤100V ) 250% of rated v	oltage.	* No evidence of damage or flash over during test.
	Strength	* Duration: 1 to 5 sec.	3	ç ç
		* Charge and discharge current less than 50n	nA.	
		* To apply voltage:		
		200V~300V ≥2 times VDC		
		500V~999V ≥1.5 times VDC		
		* Cut-off, set at 10mA		
		* TEST= 15 sec.		
		* RAMP=0		
5.	Insulation	Rated voltage:<200V		≥10GΩ
	Resistance	To apply rated voltage for max. 120 sec.		
		Rated voltage:200~630V		≥10GΩ or RxC≥100Ω-F whichever is smaller
		To apply rated voltage (500V max.) for 60 sec	).	
6.	Temperature	With no electrical load.		* Capacitance change: within ±30ppm/℃
	Coefficient	Operating temperature: -55~125℃ at 25℃		
7.	Adhesive	* Pressurizing force :		* No remarkable damage or removal of the terminations.
	Strength of	5N (≤0603) and 10N (>0603)		
	Termination	* Test time: 10±1 sec.		
8.	Vibration	* Vibration frequency: 10~55 Hz/min.		* No remarkable damage.
	Resistance	* Total amplitude: 1.5mm		* Cap change and Q/D.F.: To meet initial spec.
		* Test time: 6 hrs. (Two hrs each in three mut	ually	
		perpendicular directions.)		
9.	Solderability	* Solder temperature: 235±5℃		95% min. coverage of all metalized area.
40		* Dipping time: 2±0.5 sec.		
10.	Bending Test	* The middle part of substrate shall be pressu	-	* No remarkable damage.
		, g	•	* Cap change: within ±5.0% or ±0.5pF whichever is larger.
		the deflection becomes 1 mm and then the property that is a fact of the second to the	ressure snall be	(This capacitance change means the change of capacitance under
		maintained for 5±1 sec.	oom tomp for	specified flexure of substrate from the capacitance measured before the test.)
		* Measurement to be made after keeping at r 24±2 hrs.	oom temp. for	ine test.)
11	Resistance to	* Solder temperature: 260±5℃		* No remarkable damage.
	Soldering Heat	·		* Cap change: within ±2.5% or ±0.25pF whichever is larger.
		* Preheating: 120 to 150°C for 1 minute befor	e imme rse the	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		capacitor in a eutectic solder.		* 25% max. leaching on each edge.
		* Measurement to be made after keeping at r	oom temp. for	J
		24±2 hrs. (Class I) or 48±4 hrs. (Class II).	•	
12.	Temperature	* Conduct the five cycles according to the ten	nperatures and	* No remarkable damage.
		time.		* Cap change: within ±2.5% or ±0.25pF whichever is larger.
		Step Temp. (℃)	Time (min.)	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.
		1 Min. operating temp. +0/-3	30±3	
		:	2~3	
		3 Max. operating temp. +3/-0	30±3	
		4 Room temp.	2~3	
		* Measurement to be made after keeping at r	oom temp. for	
		24±2 hrs.		

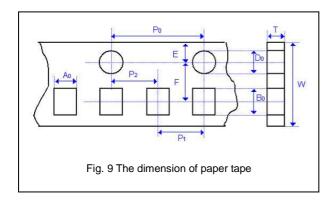


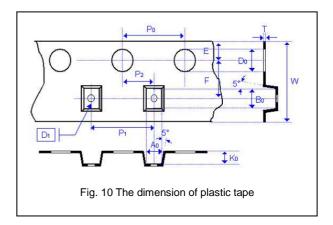
No.	Item	Test Condition	Requirements
13.	Humidity	* Test temp.: 40±2℃	* No remarkable damage.
	(Damp Heat)	* Humidity: 90~95% RH	* Cap change: within ±5.0% or ±0.5pF whichever is larger.
	Steady State	* Test time: 500+24/-0hrs.	* Q/D.F. value:
		* Measurement to be made after keeping at room temp. for	NP0: Cap≥30pF, Q≥350; 10pF≤Cap<30pF, Q≥275+2.5C
		24±2 hrs.	Cap<10pF; Q≥200+10C
			* I.R.: ≥1GΩor RxC≥50Ω-F whichever is smaller.
14.	Humidity	* Test temp.: 40±2℃	* No remarkable damage.
	(Damp Heat)	* Humidity: 90~95%RH	* Cap change: within ±7.5% or ±0.75pF whichever is larger.
	Load	* Test time: 500+24/-0 hrs.	* Q/D.F. value:
		* To apply voltage : rated voltage (Max. 500V)	NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C
		* Measurement to be made after keeping at room temp. for	* I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.
		24±2 hrs.	
15.	High	* Test temp.:	* No remarkable damage.
	Temperature	NP0: 125±3℃	* Cap change: within ±3.0% or ±0.3pF whichever is larger.
	Load	* To apply voltage:	* Q/D.F. value:
	(Endurance)	(1) <500V: 200% of rated voltage.	NP0: Cap≥30pF, Q≥350
		(2) 500V: 150% of rated voltage.	10pF≤Cap<30pF, Q≥275+2.5C
		(3) ≥630V: 120% of rated voltage.	Cap<10pF, Q≥200+10C
		* Test time: 1000+24/-0 hrs.	* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
		* Measurement to be made after keeping at room temp. for	
		24±2 hrs.	



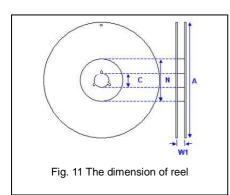
# **APPENDIXES**

#### **■ Tape & reel dimensions**





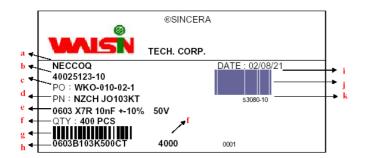
Size	0402	0603		0805	
Thickness	N	S, X	Α	В	C, D, I
A <sub>0</sub>	0.62±0.05	1.02±0.05	1.50±0.10	1.50±0.10	<1.57
B <sub>0</sub>	1.12±0.05	1.80±0.05	2.30±0.10	2.30±0.10	<2.40
Т	0.60±0.05	0.95±0.05	0.75±0.05	0.95±0.05	0.23±0.05
K <sub>0</sub>	-	-	-	-	<2.50
W	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10	8.00±0.10
P <sub>0</sub>	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10
10xP <sub>0</sub>	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10	40.0±0.10
P <sub>1</sub>	2.00±0.05	4.00±0.10	4.00±0.10	4.00±0.10	4.00±0.10
$P_2$	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05	2.00±0.05
$D_0$	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.50±0.05
D <sub>1</sub>	-	-	-	-	1.00±0.10
E	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.10
F	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05	3.50±0.05



Size	0402, 0603, 0805					
Reel size	7"	10"	13"			
С	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2			
$W_1$	8.4+1.5/-0	8.4+1.5/-0	8.4+1.5/-0			
Α	178.0±0.10	250.0±1.0	330.0±1.0			
N	60.0+1.0/-0	100.0±1.0	100±1.0			



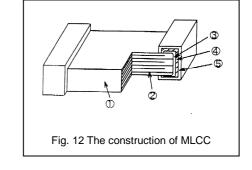
#### Description of customer label



- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- j. Order bar code including series and item numbers
- k. Serial number of label

#### Constructions

No.	Na	me	NP0*	NP0
1	Ceramic	material	CaZrO <sub>3</sub> / Ba	aTiO₃ based
2	Inner el	ectrode	AgPd alloy	Ni
3		Inner layer	Ag	Cu
4	Termination	Middle layer	Ni	
(5)		Outer layer	S	'n



 $<sup>^{\</sup>star}$  Partial NP0 items are with Ag/Ni/Sn(NME) terminations, please ref to product range for detail.

#### Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

#### Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.



#### Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of  $N_2$  within oven are recommended.

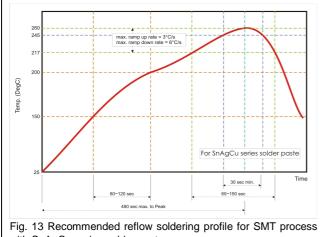


Fig. 13 Recommended reflow soldering profile for SMT process with SnAgCu series solder paste.

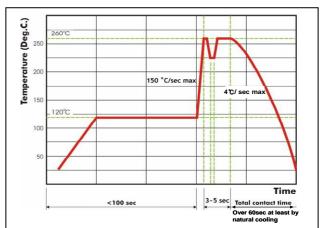


Fig. 14 Recommended wave soldering profile for SMT process with SnAgCu series solder.